

Features

- H-Bridge Motor Driver
 - -Drives One DC Motor, One Winding of
 - a Stepper Motor, or Other Loads
- Wide 6.8V to 45V Operating Voltage
- 3.6A Peak Current Drive
- PWM Control Interface
- Integrated Current Regulation
- Low-Power Sleep Mode
- VM Undervoltage Lockout (UVLO)
- Overcurrent Protection (OCP)
 - -Retry after OCP: HCR8870
 - -Latch after OCP: HCR8870B
- Thermal Shutdown (TSD)
- Automatic Fault Recovery
- SOP-8(EP)Small Package and Footprint

Applications

- Printers
- Appliances
- Industrial Equipment
- Other Mechatronics Applications

General Description

The HCR8870/HCR8870B device are the brushed-DC motor drivers for printers, appliances, industrial equipment, and other small machines. Two logic inputs control the H-bridge driver, which consists of four N-channel MOSFETs that can control motors bidirectionally with up to 3.6-A peak current. The inputs can be pulse width modulated (PWM) to control motor speed, using a choice of currentdecay modes. Setting both inputs slow enter a low-power sleep mode.

The HCR8870/HCR8870B devices feature integrated current regulation, based on the analog input VREF and the voltage on the ISEN pin, which is proportional to motor current through an external sense resistor.

The ability to limit current to a known level can significantly reduce the system power requirements and bulk capacitance needed to maintain stable voltage, especially for motor startup and stall conditions.

The devices are fully protected from faults and short circuits, including UVLO, OCP, and TSD.



SOP-8(EP)

Figure 1. Package Type of HCR8870/HCR8870B



Pin Configuration

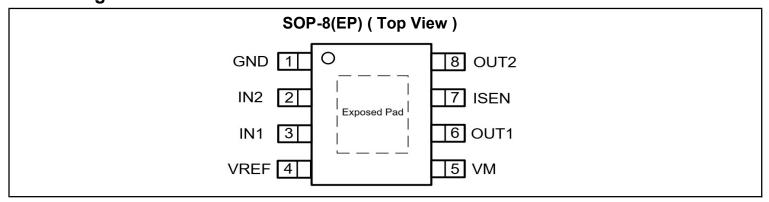
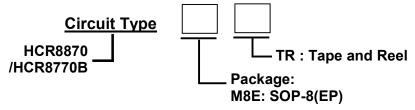


Figure 2. Pin Configuration of HCR8870/HCR8870B (Top View)

Pin Function Table

Nome	Pin	Eurotion Deparintion					
Name	SOP-8(EP)	Function Description					
GND	1	Logic ground. Connect to board ground					
IN2	2	Logic inputs. Controls the H-bridge output. Has internal pulldowns.					
IN1	3	Logic inputs. Controls the H-bridge output. Has internal pulldowns.					
VREF	4	Analog input. Apply a voltage between 0.3V to 5V.					
VM	5	6.8V to 45V power supply. Connect a 0.1µF bypass capacitor to ground, as well as sufficient bulk capacitance, rated for the VM voltage.					
OUT1	6	H-bridge output. Connect directly to the motor or other inductive load.					
ISEN	7	High-current ground path. If using current regulation, connect ISEN to a resistor (lowvalue, high-power-rating) to ground. If not using current regulation, connect ISEN directly to ground					
OUT2	8	H-bridge output. Connect directly to the motor or other inductive load.					
	EP	Exposed Pad, Connect to board ground.					

Ordering Information



Ordering Code

Part Number	Marking ID ^{note2}	Operating Junction Temperature Range	Package	Quantity per Reel
HCR8870M8ETR	HCR8870XX	-40'C to +125'C	SOP-8(EP)	3000pcs/TR
HCR8870BM8ETR	HCR8870BXX	-40'C to +125'C	SOP-8(EP)	3000pcs/TR

Note 2: the "XX" is lot number code.



Functional Block Diagram

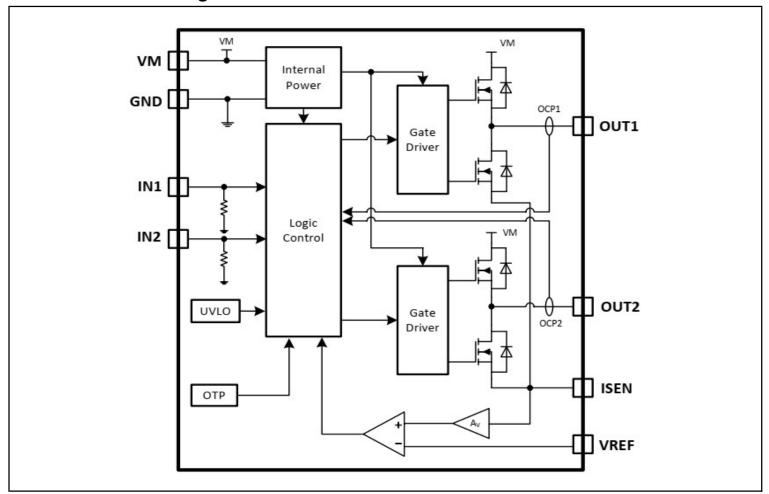


Figure 3. Functional Block Diagram

Typical Application Circuit

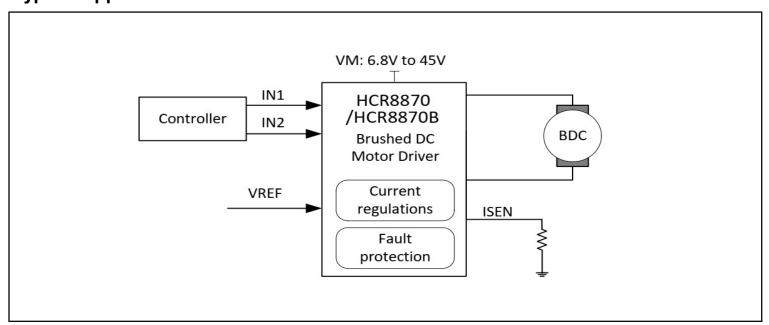


Figure 4. Basic Application Circuit



Absolute Maximum Ratings

Over Operating free-air temperature range (unless otherwise (1/2)

Parameter	Symbol	Value	Unit
Input Supply Voltage Range (3)	VM	-0.3 to +45	V
Logic Input Voltage(IN1, IN2)	Vi	-0.3 to +6	V
reference input pin voltage(Vref)	VREF	-0.3 to +6	V
Continuous Phase node Pin Voltage(OUT1,OUT2)	Vouт	-0.7 to (VM+0.7)	v
Current sense input pin voltage(ISEN)	VSEN	-0.5 to 1	V
Output Current (100% duty cycle)	lout	0 to 3.5	Α
Junction-to-ambient thermal resistance (4)	Reja	41.1	'C/W
Junction-to-case thermal resistance (4)	Rejc	23.1	'C/W
Storage Temperature Range	Тѕтс	-65 to +150	'C
Operating Junction Temperature (5)	TJ	-40 to +150	'C
Lead Temperature (Soldering, 10s)	TLEAD	260	'C
Human Body Model for all pins	VESD_HBM	±2000	V
Charge Device Model for all pins	VESD_CDM	200	v

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

- 2: All voltages are with respect to the GND pin.
- 3: To protect the chip, the VM voltage should not exceed 16V under any operating conditions and the VM VM capacitance should be increased to suppress spikes when using inductive loads.
- 4: The package thermal impedance is calculated in accordance with JESD-51.
- 5: TJ is calculated from the ambient temperature TA and power dissipation PD according to the following formula: TJ = TA + PD x θ JA. The maximum allowable continuous power dissipation at any ambient temperature is calculated by PD (MAX) = (TJ(MAX)-TA)/ θ JA.

Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted) (6).

Parameter	Symbol	Test Condition	Min	Туре	Max	Unit
Power supply voltage Range	VM		6.8	-	45	٧
Logic Input Voltage(IN1,IN2)	VI		0	-	5.5	٧
Logic Input PWM frequency(IN1,IN2)	fPWM		0	-	100	KHz
Peak output current	I peak		0	-	3.6	Α
Operating Junction Temperature Range	TJ		-40	-	+125	Ċ

Note 6: Power dissipation and thermal limits must be observed.



Electrical Characteristics

(TA = +25°C, over recommended operating condition unless otherwise noted)

(1A = 120 0, Over recommended op						
Parameter	er Symbol Test Condition		Min.	Тур.	Max.	Unit
Power Supply (VM)						
VM Operating Voltage	VM		6.8	-	45	٧
VM Operating Supply Current	Ivм	VM=12V	-	3	10	mA
VM Sleep Mode Supply Current	IVMSLEEP	VM=12V	-	-	1	uA
Turn-on time ^{note6}	ton	VM>VUVLO with IN1 or IN2 high	-	30	50	us
logic-Level Inputs (IN1, IN2)						
Input Logic-Low Voltage	VIL	-	-	-	0.5	٧
Input Logic-High Voltage	ViH	-	1.6	-	-	٧
Input Logic hysteresis	VHYS	-	-	0.5	-	V
Input Logic Low Current	lıL	VIN=0V	-1.0	-	1.0	uA
Input Logic High Current	lін	VIN=3.3V	-	62	-	uA
Pulldown Resistance	RPD	to GND	-	53	-	ΚΩ
Propagation delay	t PD	Inx to OUTx change	-	0.7	-	us
Time to sleep	tsleep	Inputs low to sleep	-	1	1.5	ms
MOTOR Driver Outputs (OUT1, C	UT2)					
High-side FET ON-Resistance	RDS(ON)_High	VM=24V, IOUT=1A	-	430	-	mΩ
Low-side FET ON-Resistance	RDS(ON)_Low	VM=24V, IOUT=1A	-	480	-	mΩ
Output dead time	tDEAD	-	-	220	•	ns
Body diode forward voltage	Vd	IOUT=1A	-	0.9	•	٧
Current Regulation						
ISEN gain	AV	VREF=2.5V	-	10	-	V/V
PWM off-time	toff	-	-	25	-	us
PWM blanking time	t BLANK	-	-	2	•	us
Protection Circuits						
VM undervoltage Lockout	VUVLO_fall	WM falls until UVLO triggers	-	6.2	-	٧
Vivi unuei voltage Lockout	VUVLO_rise	WM rises until operation recovers	-	6.5	-	٧
VM undervoltage hysteresis	Vuv_HYS	Rising to falling threshold	-	240	-	mV
Overcurrent Protection Trip level	ІОСР	-	-	4.5	-	Α
Overcurrent Deglitch Time	tocp	-	-	1.8	-	us
Overcurrent Retry Time	tretry	-	-	3	-	ms
L						<u> </u>



Electrical Characteristics(con.)

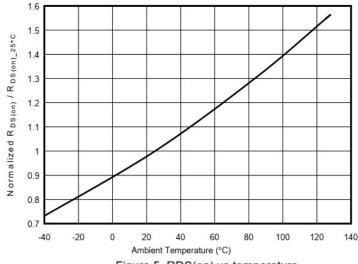
(TA = +25°C, over recommended operating condition unless otherwise noted)

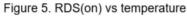
Parameter	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Protection Circuits						
Thermal Shutdown threshold ^{note7}	TSD		-	150	-	'C
Thermal Shutdown hysteresis ^{note7}	THYS		-	30	-	'C

Note 6. ton applies when the device initially powers up, and when it exits sleep mode.

7. Thermal shutdown threshold and hysteresis are guaranteed by design.

Typical Characteristics





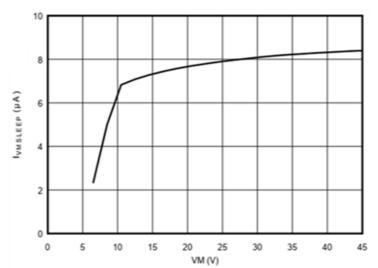


Figure 6. IVMSLEEP vs VM at 25'C



Detailed Deacription

Overview

The HCR8870/HCR8770B devices are optimized 8 -pin devices for driving brushed DC motors with 6.8V to 45V and up to 3.6A peak current. The integrated current regulation restricts motor current to a predefined maximum. Two logic inputs control the H-bridge driver, which consists of four N-channel MOSFETs that have a typical RDS(ON) of 0.9 Ω (including one high-side and one low-side FET). A single-power input, VM, serves as both

device power and the motor winding bias voltage. The integrated charge pump of the device boosts VM internally and fully enhances the high-side FETs. Motor speed can be controlled with pulse-width modulation, at frequencies between 0 to 100kHz. The devices have an integrated sleep mode that is entered by bringing both inputs low. An assortment of protection features prevents the device from being damaged if a system fault occurs

Feature Description

Bridge Control

The HCR8870/HCR8870B output consists of four N-channel MOSFETs that are designed to drive high current. These outputs are controlled by the two logic inputs IN1 and IN2 as listed in Table 1.

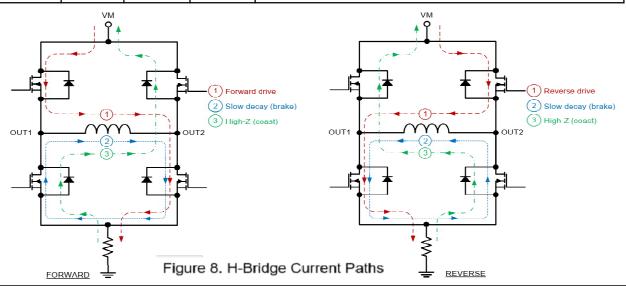
The inputs can be set to static voltages for 100% duty cycle drive, or they can be pulse-width modulated (PWM) for variable motor speed. When using PWM, switching between driving and braking

Bridge Control(con.)

typically works best. For example, to drive a motor forward with 50% of the maximum RPM, IN1 = 1 and IN2 = 0 during the driving period, and IN1 = 1 and IN2 = 1 during the other period. Alternatively, the coast mode (IN1 = 0, IN2 = 0) for fast current decay is also available. The input pins can be powered before VM is applied.

Table 1. H-Brifge Control

IN1	IN2	OUT1	OUT2	Description
0	0	High-Z	High-Z	Coast; H-bridge disabled to High-Z(sleep entered after 1 ms)
0	1	L	Н	Reverse (Current OUT2 -> OUT1)
1	0	Н	L	Forward (Current OUT1 -> OUT2)
1	1	L	L	Brake; low-side slow decay





Feature Description(con.)

Sleep Mode

When the IN1 and IN2 pins are both low for time tsleep (typically 1 ms), the HCR8870/HCR8870B device enters a low power sleep mode, where the outputs remain High-Z and the device uses IVMSLEEP (μ A) of current. If the device is powered up while both inputs are low, it immediately enters sleep mode. After the IN1 or IN2 pins are high for at least 5 μ s, the device is operational 50 μ s (tON) later.

Current Regulation

In HCR8870/HCR8870B, motor peak current can be limited by the analog reference input VREF and the resistance of external sense resistor on the ISEN pin according to the below equation:

$$I_{TRIP} (A) = \frac{V_{ILIM} (kV)}{R_{ILIM} (k\Omega)} = \frac{64(kV)}{R_{ISFN} (k\Omega)}$$

VM Undervoltage Lockout (UVLO)

If at any time the voltage on the VM pin falls below the undervoltage-lockout threshold voltage, all FETs in the H-bridge will be disabled. Operation resumes when VM rises above the UVLO threshold.

Overcurrent Protection (OCP)

If the output current exceeds the OCP threshold, IOCP, for longer than tOCP, all FETs in the H-bridge are disabled.

As to HCR8870, after a duration of tRETRY, the H-bridge is re-enabled according to the state of the INx pins. If the overcurrent fault is still present, the cycle repeats; otherwise normal device operation resumes.

As to HCR8870B, after OCP events, the device is latched and it can only be reset by putting the device into sleep mode or by restarting the power of VM.

Thermal Shutdown (TSD)

If the die temperature exceeds safe limits, all FETs in the H-bridge are disabled. After the die temperature has fallen to a safe level, operation automatically resumes.

Device Functional Modes

The HCR8870/HCR8870B devices can be used in multiple ways to drive a brushed DC motor.

PWM With Current Regulation

This scheme uses all of the capabilities of the device. The ITRIP current is set above the normal operating current, and high enough to achieve an adequate spin-up time, but low enough to constrain current to a desired level. Motor speed is controlled by the duty cycle of one of the inputs, while the other input is static. Brake or slow decay is typically used during the off-time.

PWM Without Current Regulation

If current regulation is not required, the ISEN pin should be directly connected to the PCB ground plane. The VREF voltage must still be 0.3V to 5 V, and larger voltages provide greater noise margin. This mode provides the highest-possible peak current which is up to 3.6 A for a few hundred milliseconds (depending on PCB characteristics and the ambient temperature). If current exceeds 3.6A, the device might reach overcurrent protection (OCP) or overtemperature shutdown (TSD). If that happens, the device disables and protects itself for about 3ms (tRETRY) and then resumes normal operation.

Static Inputs with Current Regulation
The IN1 and IN2 pins can be set high and low for
100% duty cycle drive, and ITRIP can be used to
control the current of the motor, speed, and torque
capability.



Feature Description(con.)

VM Control

In some systems, varying VM as a means of changing motor speed is desirable. In application, local bulk capacitance is needed on VM to GND to stable VM voltage during the operation with motor

starts up or stops. At least a 47µF bulk capacitor with voltage rating of operation voltage is recommended. However, the system-level testing is required to determine the appropriate size bulk capacitors.

APPLICATION INFORMATION

Application information

The HCR8870/HCR8870B devices are typically used to drive one brushed DC motor as below:

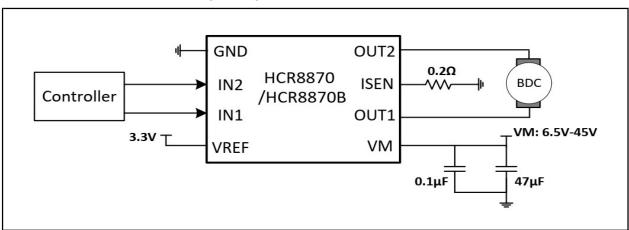


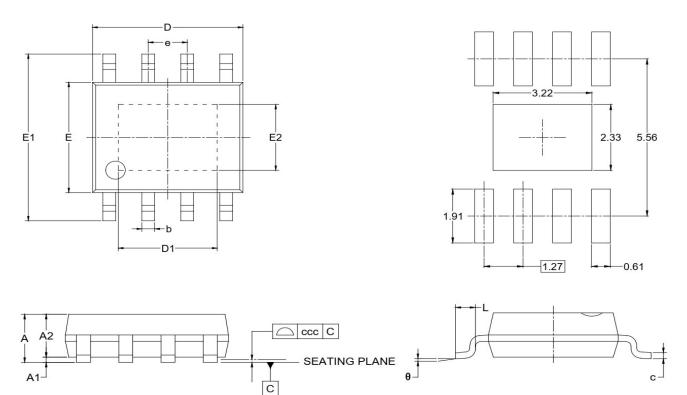
Figure 9. Type Application Circuit



Mechanical Dimensions

M8E PKG: SOP-8(EP)

unit:mm



Symbol		Dimensions In Millimeters						
, , , , , , , , , , , , , , , , , , , ,	MIN	MOD	MAX					
Α			1.700					
A1	0.000	-1	0.150					
A2	1.250	-	1.650					
b	0.330	-	0.510					
С	0.170	-:	0.250					
D	4.700	-	5.100					
D1	3.020	-	3.420					
E	3.800	-	4.000					
E1	5.800	-	6.200					
E2	2.130	-	2.530					
е	1.27 BSC							
L	0.400	=	1.270					
θ	0°	-	8°					
ccc		0.100						

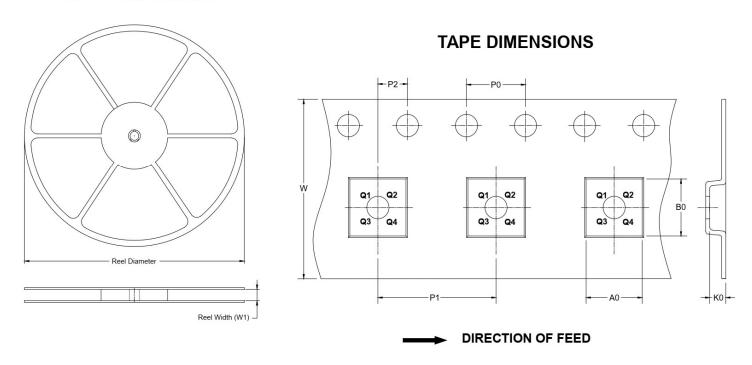
NOTE:

- 1. Plastic or metal protrusions of 0.15mm maximum per side are not included.
- 2. BSC (Basic Spacing between Centers), "Basic" spacing is nominal.
- 3. This drawing is subject to change without notice.



TAPE AND REEL INFORMATION

REEL DIMENSIONS

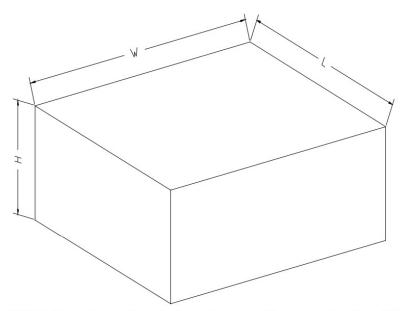


NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SOP-8(EP)	13"	12.4	6.4	5.4	2.1	4.0	8.0	2.0	12.0	Q1

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)		Height (mm)	Pizza/Carton	
13″	386	280	370	5	